NSN 5961-01-344-5690

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-344-5690 **Inclosure Material:** Plastic or ceramic **Overall Length:** 15.8 millimeters **Terminal Length:** 13.5 millimeters **Overall Height:** 4.5 millimeters **Overall Width:** 10.3 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 300.0 repetitive peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 30.00 amperes forward current, average all semiconductor device diode **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No